

Freescale Semiconductor

MPX2010 Rev 13, 10/2008

10 kPa On-Chip Temperature **Compensated and Calibrated Silicon Pressure Sensors**

The MPX2010 series silicon piezoresistive pressure sensors provide a very accurate and linear voltage output directly proportional to the applied pressure. These sensors house a single monolithic silicon die with the strain gauge and thin film resistor network integrated. The sensor is laser trimmed for precise span, offset calibration and temperature compensation.

Features

- Temperature Compensated over 0°C to +85°C
- Ratiometric to Supply Voltage
- Differential and Gauge Options
- Available in Easy-to-Use Tape & Reel

MPX2010 Series

0 to 10 kPa (0 to 1.45 psi) 25 mV Full Scale (Typical)

Application Examples

- Respiratory Diagnostics
- Air Movement Control
- Controllers
- Pressure Switching

			OI	RDERING	INFORM	ATION			
Device Name	Package	Case		# of Ports	3		Pressure Type)	Davisa Markina
Device Name	Options	No.	None	Single	Dual	Gauge	Differential	Absolute	Device Marking
Small Outline Pag	kage (MPXV201	0 Series)							
MPXV2010GP	Tray	1369		•		•			MPXV2010GP
MPXV2010DP	Tray	1351			•				MPXV2010DP
Unibody Package	(MPX2010 Serie	es)							
MPX2010D	Tray	344	•				•		MPX2010D
MPX2010DP	Tray	344C			•		•		MPX2010DP
MPX2010GP	Tray	344B		•		•			MPX2010GP
MPX2010GS	Tray	344E		•		•			MPX2010D
MPX2010GSX	Tray	344F		į		•			MPX2010D
MPAK Package (I	MPXM2010 Serie	s)						•	•
MPXM2010D	Rail	1320	•				•		MPXM2010D
MPXM2010DT1	Tape and Reel	1320	•				•		MPXM2010D
MPXM2010GS	Rail	1320A		•		•			MPXM2010GS
MPXM2010GST1	Tape and Reel	1320A		•		•			MPXM2010GS

SMALL OUTLINE PACKAGES



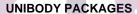


MPXV2010GP **CASE 1369-01**

MPXV2010DP **CASE 1351-01**

MPXM2010D/DT1 CASE 1320-02

MPXM2010GS/GST1 CASE 1320A-02





MPX2010D **CASE 344-15**



MPX2010GP **CASE 344B-01**



MPX2010DP **CASE 344C-01**



MPX2010GS CASE 344E-01



MPX2010GSX **CASE 344F-01**





Operating Characteristics

Table 1. Operating Characteristics ($V_S = 10 V_{DC}$, $T_A = 25$ °C unless otherwise noted, P1 > P2)

Characteristic	Symbol	Min	Тур	Max	Units
Pressure Range ⁽¹⁾	P _{OP}	0	_	10	kPa
Supply Voltage ⁽²⁾	Vs	_	10	16	V_{DC}
Supply Current	Io	_	6.0	_	mAdc
Full Scale Span ⁽³⁾	V _{FSS}	24	25	26	mV
Offset ⁽⁴⁾	V _{OFF}	-1.0	_	1.0	mV
Sensitivity	ΔV/ΔΡ	_	2.5	_	mV/kPa
Linearity	_	-1.0	-	1.0	%V _{FSS}
Pressure Hysteresis (0 to 10 kPa)	-	_	±0.1	_	%V _{FSS}
Temperature Hysteresis (–40°C to +125°C)	_	_	±0.5	_	%V _{FSS}
Temperature Coefficient on Full Scale Span	TCV _{FSS}	-1.0	_	1.0	%V _{FSS}
Temperature Coefficient on Offset	TCV _{OFF}	-1.0	_	1.0	mV
Input Impedance	Z _{IN}	1300	-	2550	Ω
Output Impedance	Z _{OUT}	1400		3000	Ω
Response Time ⁽⁵⁾ (10% to 90%)	t _R	_	1.0	_	ms
Warm-Up Time	_	-	20	_	ms
Offset Stability ⁽⁶⁾	_	_	±0.5	_	%V _{FSS}

- 1. 1.0 kPa (kiloPascal) equals 0.145 psi.
- 2. Device is ratiometric within this specified excitation range. Operating the device at a different range may induce additional error due to device self-heating.
- Full Scale Span (V_{FSS}) is defined as the algebraic difference between the output voltage at full rated pressure and the output voltage at the minimum rated pressure.
- 4. Offset (V_{OFF}) is defined as the output voltage at the minimum rated pressure.
- 5. Response Time is defined as the time for the incremental change in the output to go from 10% to 90% of its final value when subjected to a specified step change in pressure.
- 6. Offset stability is the product's output deviation when subjected to 1000 hours of Pulsed Pressure, Temperature Cycling with Bias Test.





Maximum Ratings

Table 2. Maximum Ratings⁽¹⁾

Rating	Symbol	Value	Unit
Maximum Pressure (P1 > P2)	P _{MAX}	75	kPa
Burst Pressure (P1 > P2)	P _{BURST}	100	kPa
Storage Temperature	T _{STG}	-40 to +125	°C
Operating Temperature	T _A	-40 to +125	°C

^{1.} Exposure beyond the specified limits may cause permanent damage or degradation to the device.

Voltage Output versus Applied Differential Pressure

The output voltage of the differential or gauge sensor increases with increasing pressure applied to the pressure side (P1) relative to the vacuum side (P2). Similarly, output voltage increases as increasing vacuum is applied to the vacuum side (P2) relative to the pressure side (P1).

Figure 1. shows a block diagram of the internal circuitry on the stand-alone pressure sensor chip.

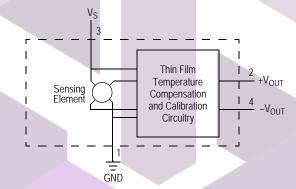


Figure 1. Temperature Compensated and Calibrated Pressure Sensor Schematic



On-Chip Temperature Compensation and Calibration

Figure 2. shows the output characteristics of the MPX2010 series at 25°C. The output is directly proportional to the differential pressure and is essentially a straight line.

The effects of temperature on full scale span and offset are very small and are shown under Operating Characteristics.

This performance over temperature is achieved by having both the shear stress strain gauge and the thin-film resistor circuitry on the same silicon diaphragm. Each chip is dynamically laser trimmed for precise span and offset calibration and temperature compensation.

Figure 3. illustrates the differential/gauge die in the basic chip carrier (Case 344). A silicone gel isolates the die surface and wire bonds from the environment, while allowing the pressure signal to be transmitted to the silicon diaphragm.

The MPX2010 series pressure sensor operating characteristics and internal reliability and qualification tests are based on use of dry air as the pressure media. Media other than dry air may have adverse effects on sensor

performance and long term reliability. Contact the factory for information regarding media compatibility in your application.

LINEARITY

Linearity refers to how well a transducer's output follows the equation: $V_{out} = V_{off} + \text{sensitivity x P}$ over the operating pressure range. There are two basic methods for calculating nonlinearity: (1) end point straight line fit (see Figure 4.) or (2) a least squares best line fit. While a least squares fit gives the "best case" linearity error (lower numerical value), the calculations required are burdensome.

Conversely, an end point fit will give the "worst case" error (often more desirable in error budget calculations) and the calculations are more straightforward for the user. Freescale's specified pressure sensor linearities are based on the end point straight line method measured at the midrange pressure.

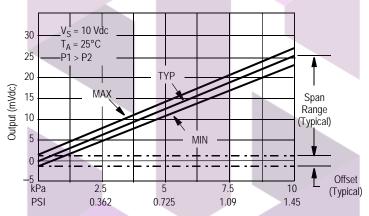


Figure 2. Output vs. Pressure Differential

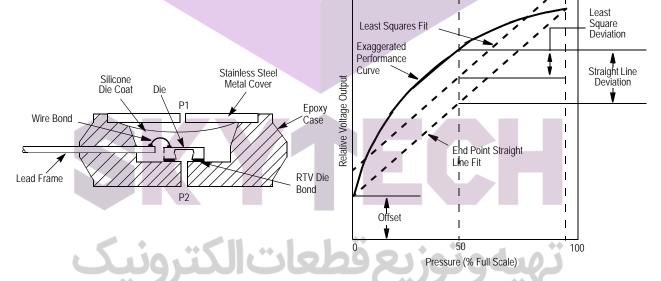


Figure 3. Unibody Package: Cross Sectional Diagram (not to scale)

Figure 4. Linearity Specification Comparison



PRESSURE (P1)/VACUUM (P2) SIDE IDENTIFICATION TABLE

Freescale designates the two sides of the pressure sensor as the Pressure (P1) side and the Vacuum (P2) side. The Pressure (P1) side is the side containing silicone gel which isolates the die from the environment. The pressure sensor is designed to operate with positive differential pressure applied, P1 > P2.

The Pressure (P1) side may be identified by using the following table.

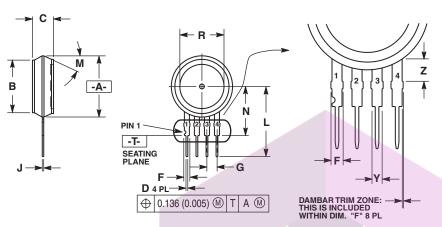
Table 3. Pressure (P1) Side Delineation

Part Number	Case Type	Pressure (P1) Side Identifier
MPX2010D	344	Stainless Steel Cap
MPX2010DP	344C	Side with Part Marking
MPX2010GP	344B	Side with Port Attached
MPX2010GS	344E	Side with Port Attached
MPX2010GSX	344F	Side with Port Attached
MPXV2010GP	1369	Side with Port Attached
MPXV2010DP	1351	Side with Part Marking
MPXM2010D/DTI	1320	Side with Part Marking
MPXM2010GS/GSTI	1320A	Side with Port Attached







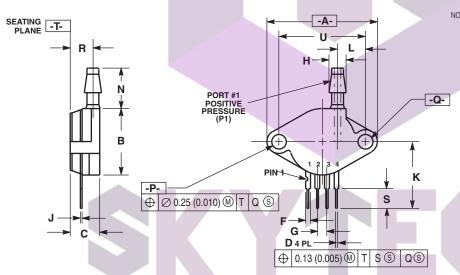


NOTES:

- DIMENSIONING AND TOLERANCING PER ASME
- DIMENSIONING AND TOLEHANCING PEH ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: INCH.
 DIMENSION -A- IS INCLUSIVE OF THE MOLD STOP RING. MOLD STOP RING NOT TO EXCEED. 16.00 (0.630).

	INC	HES	MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α	0.595	0.630	15.11	16.00		
В	0.514	0.534	13.06	13.56		
C	0.200	0.220	5.08	5.59		
D	0.016	0.020	0.41	0.51		
F	0.048	0.064	1.22	1.63		
G	0.100	BSC	2.54 BSC			
7	0.014	0.016	0.36	0.40		
L	0.695	0.725	17.65	18.42		
M	30°	NOM	30° NOM			
N	0.475	0.495	12.07	12.57		
R	0.430	0.450	10.92	11.43		
Υ	0.048	0.052	1.22	1.32		
7	0.106	0.118	2.68	3.00		

CASE 344-15 ISSUE AA UNIBODY PACKAGE



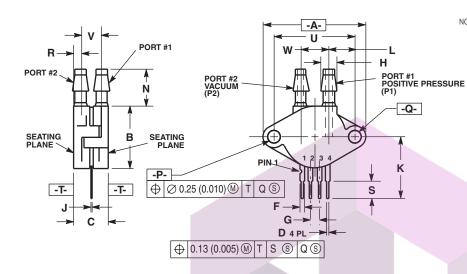
NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.

	- 1	NC	HES	MILLI	MET	ERS
DIM	MII	V	MAX	MIN	N	IAX
Α	1.14	5	1.175	29.08	2	9.85
В	0.68	5	0.715	17.40	18	8.16
С	0.30	5	0.325	7.75	8	.26
D	0.01	6	0.020	0.41	0	1.51
F	0.048		0.064	1.22	1	.63
G	0.100 BSC			2.54 BSC		
Н	0.182		0.194	4.62	4	.93
J	0.01	4	0.016	0.36	0	1.41
K	0.69	0.695 0.725 1		17.65	- 18	8.42
L	0.29	0	0.300	7.37	7	.62
N	0.42	0.	0.440	10.67	11	1.18
Р	0.15	3	0.159	3.89	4	.04
Q	0.15	3	0.159	3.89	4	.04
R	0.23	0	0.250	5.84	6	.35
S	0.22	20 0.240		5.59 6.1		.10
Ū	0	.910	BSC	23.	11 BS	c _

CASE 344B-01 ISSUE B **UNIBODY PACKAGE**



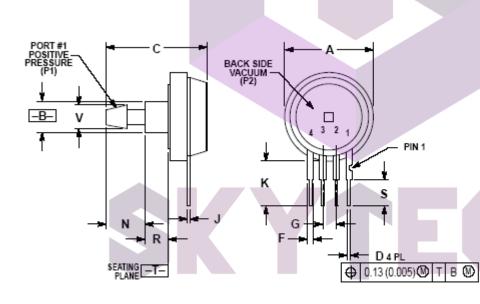


- DIMENSIONING AND TOLERANCING PER ANSI
- 2. CONTROLLING DIMENSION: INCH.

	INCI	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	1.145	1.175	29.08	29.85
В	0.685	0.715	17.40	18.16
С	0.405	0.435	10.29	11.05
D	0.016	0.020	0.41	0.51
F	0.048	0.064	1.22	1.63
G	0.100	BSC	2.54	BSC
Н	0.182	0.194	4.62	4.93
J	0.014	0.016	0.36	0.41
K	0.695	0.725	17.65	18.42
L	0.290	0.300	7.37	7.62
N	0.420	0.440	10.67	11.18
Р	0.153	0.159	3.89	4.04
Q	0.153	0.159	3.89	4.04
R	0.063	0.083	1.60	2.11
S	0.220	0.240	5.59	6.10
U	0.910	BSC	23.11 BSC	
٧	0.248	0.278	6.30	7.06
W	0.310	0.330	7.87	8.38

STYLE 1: PIN 1. GROUND 2. + OUTPUT 3. + SUPPLY 4. - OUTPUT

CASE 344C-01 ISSUE B UNIBODY PACKAGE



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

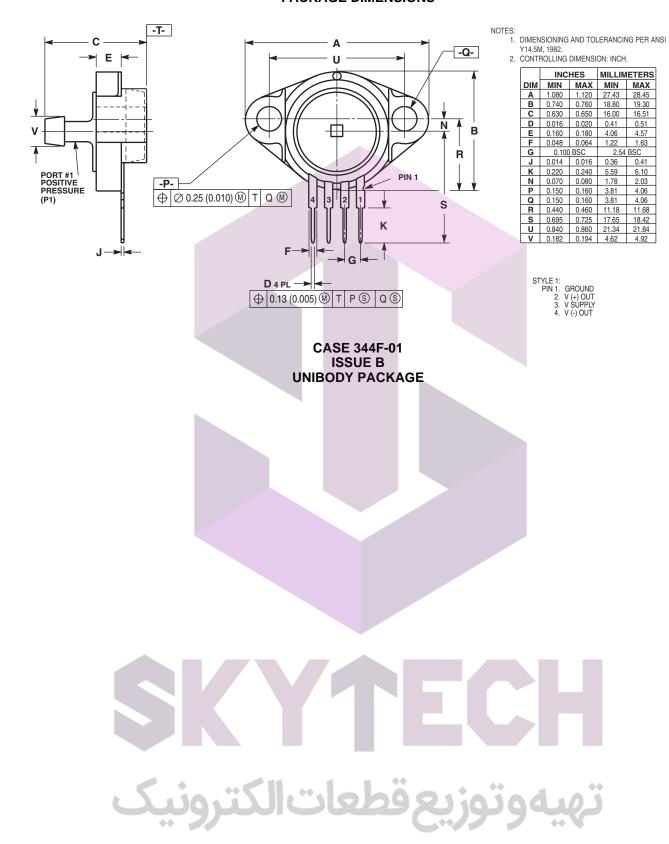
	INC	HES	MILLIM	ETER\$	
DIM	MIN	MAX	MIN	MAX	
Α	0.690	0.720	17.53	18.28	
В	0.245	0.255	6.22	6.48	
С	0.780	0.820	19.81	20.82	
О	0.016	0.020	0.41	0.51	
F	0.048	0.064	1.22	1.63	
G	0.100	BSC	2.54 BSC		
_	0.014	0.016	0.36	0.41	
K	0.345	0.375	8.76	9.53	
N	0.300	0.310	7.62	7.87	
R	0.178	0.186	4.52	4.72	
- 5	0.220	0.240	5.59	6.10	
v	0.400	0.404	4.82	4.02	

STYLE 1:

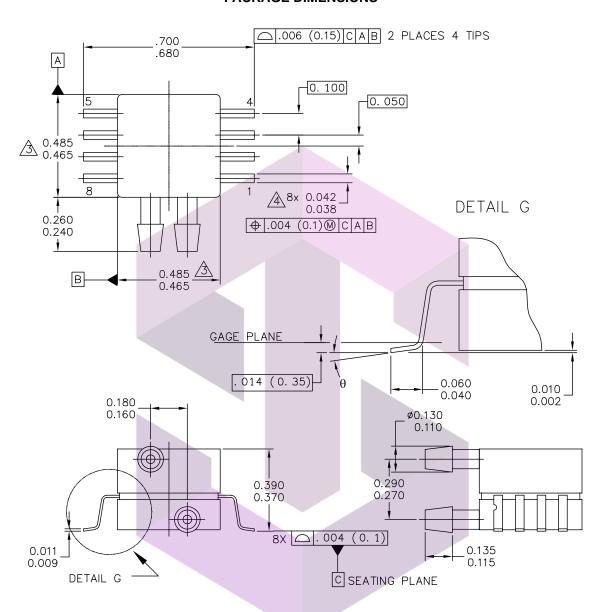
GROUND + OUTPUT + SUPPLY - OUTPUT

ISSUE B UNIBODY PACKAGE









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8 LD SNSR, DUAL	PORT CASE NUMBE STANDARD: N		27 JUL 2005

PAGE 1 OF 2

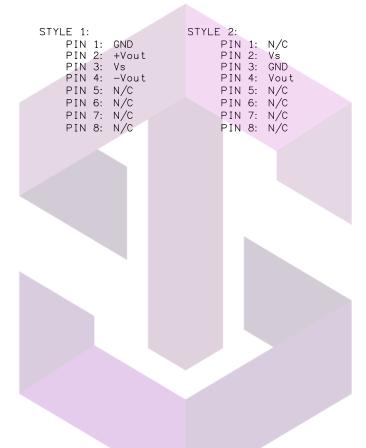
CASE1351-01 ISSUE A SMALL OUTLINE PACKAGE



NOTES:

- 1. CONTROLLING DIMENSION: INCH
- 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
- DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PPROTRUSIONS.

 MOLD FLASH AND PROTRUSIONS SHALL NOT EXCEED .006 PER SIDE.
- DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .008 MAXIMUM.

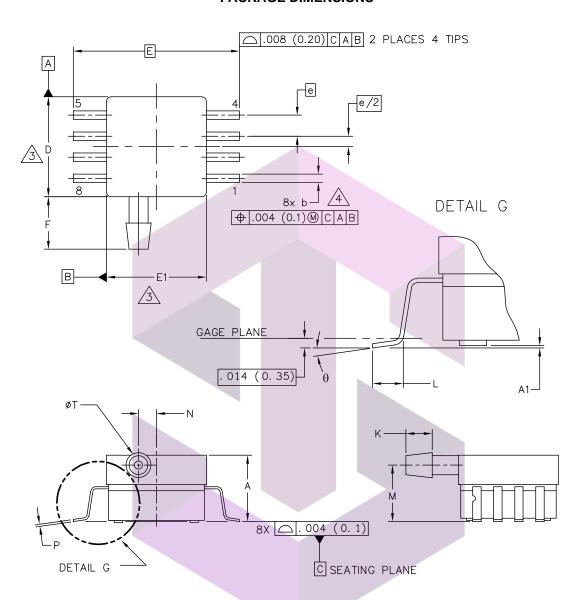


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8 LD SOP, SIDE PO	ORT CASE NUMBER	R: 1369–01	24 MAY 2005
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- 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
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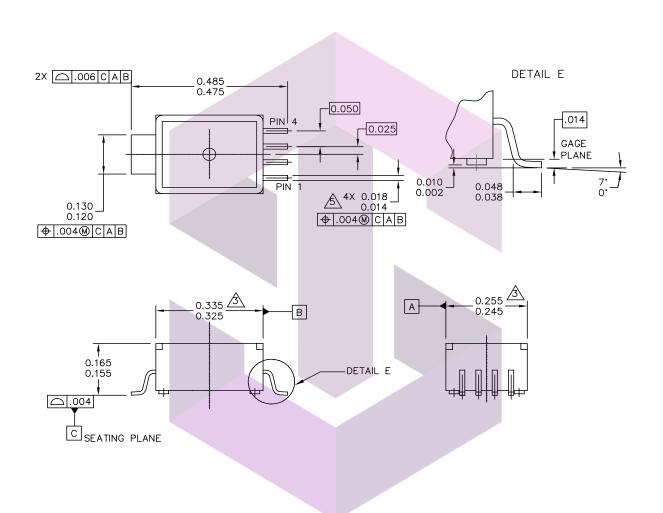
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b	. 038	. 042	0. 96	1. 07	-				
D	. 465	. 485	11. 81	12. 32	_				
E	. 717	BSC	18. 2 ⁻	I BSC	_				
E1	. 465	. 485	11. 81	12. 32	_				
e	. 100	BSC	2. 54	BSC	_				
F	. 245	. 255	6. 22	6. 47	_				
K	. 120	. 130	3. 05	3. 30	-				
L	. 061	. 071	1. 55	1. 80	-				
М	. 270	. 290	6. 86	7. 36	-				
N	. 080	. 090	2. 03	2. 28	_				
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4. ALL VERTICAL SURFACES TO BE 5' MAXIMUM.

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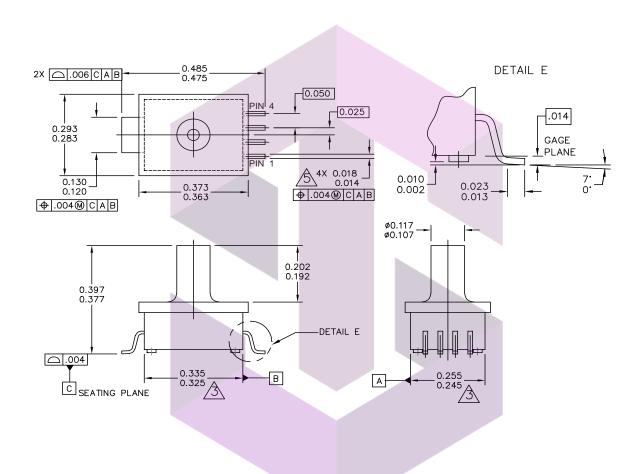
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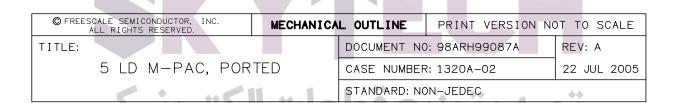
PIN 1: GND
PIN 2: +Vout
PIN 3: Vs
PIN 4: -Vout

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CASE 1320-02 ISSUE A MPAK







CASE 1320A-02 ISSUE A MPAK



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4. ALL VERTICAL SURFACES TO BE 5" MAXIMUM.

DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .008 MAXIMUM.



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